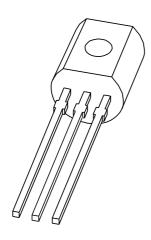
DISCRETE SEMICONDUCTORS

DATA SHEET



BC559 PNP general purpose transistor

Product specification Supersedes data of 1997 Jun 03 1999 May 28





PNP general purpose transistor

BC559

FEATURES

• Low current (max. 100 mA)

• Low voltage (max. 30 V).

APPLICATIONS

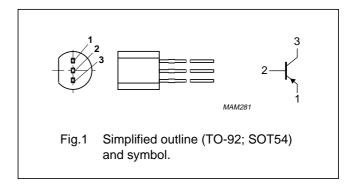
• General purpose switching and amplification.

DESCRIPTION

PNP transistor in a TO-92 (SOT54) plastic package. NPN complement: BC549.

PINNING

PIN	DESCRIPTION
1	emitter
2	base
3	collector



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-30	V
V _{CEO}	collector-emitter voltage	open base	_	-30	V
V _{EBO}	emitter-base voltage	open collector	_	- 5	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-200	mA
I _{BM}	peak base current		_	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	250	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

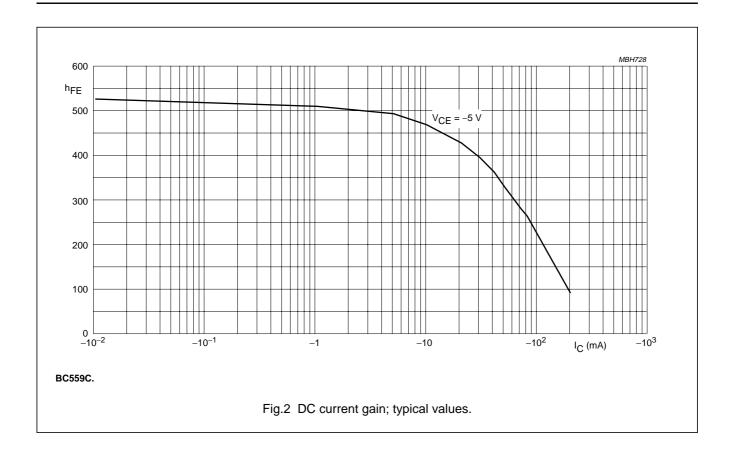
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	$I_E = 0; V_{CB} = -30 \text{ V}$	_	-1	-15	nA
		$I_E = 0$; $V_{CB} = -30 \text{ V}$; $T_j = 150 ^{\circ}\text{C}$	_	_	-4	μΑ
I _{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -5 \text{ V}$	_	_	-100	nA
h _{FE}	DC current gain; BC559C	$I_C = -2$ mA; $V_{CE} = -5$ V; see Fig.2	420	_	800	
V _{CEsat}	collector-emitter saturation	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	_	-60	-300	mV
	voltage	$I_C = -100 \text{ mA}; I_B = -5 \text{ mA}$	_	-180	-650	mV
V _{BEsat}	base-emitter saturation voltage	$I_C = -10 \text{ mA}$; $I_B = -0.5 \text{ mA}$; note 1	_	-750	_	mV
		$I_C = -100 \text{ mA}; I_B = -5 \text{ mA}; \text{ note 1}$	_	-930	_	mV
V _{BE}	base-emitter voltage	$I_C = -2 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ note } 2$	-600	-650	-750	mV
		$I_C = -10 \text{ mA}$; $V_{CE} = -5 \text{ V}$; note 2	_	_	-820	mV
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	_	4	_	pF
f _T	transition frequency	$I_E = -10 \text{ mA}; V_{CB} = -5 \text{ V}; f = 100 \text{ MHz}$	100	_	_	MHz
F	noise figure; BC559C	$I_{C} = -200 \mu\text{A}; V_{CE} = -5 V; R_{S} = 2 k\Omega;$ $f = 30 Hz to 15.7 kHz$	_	_	4	dB
		$I_{C} = -200 \ \mu A; \ V_{CE} = -5 \ V; \ R_{S} = 2 \ k\Omega; \ f = 1 \ kHz; \ B = 200 \ Hz$	_	_	4	dB

Notes

- 1. V_{BEsat} decreases by about -1.7 mV/K with increasing temperature.
- 2. V_{BE} decreases by about -2 mV/K with increasing temperature.

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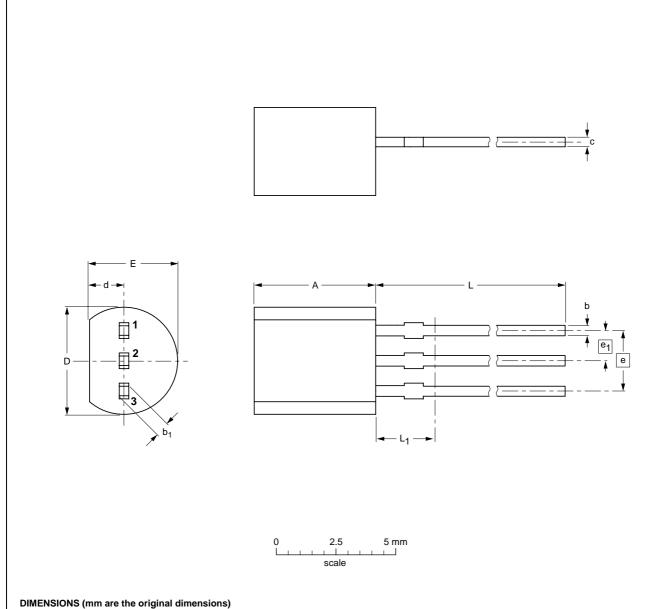
PNP general purpose transistor

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	A	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

	OUTLINE		REFERENCES			EUROPEAN ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
	SOT54		TO-92	SC-43			97-02-28

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DEFINITIONS

Data sheet status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or			

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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